## What is claimed is:

1.	A lid	uid-crystal	display	device	comprising:
<b>±</b> •	·	RUTU CIVSCUI	$\alpha \pm 3D \pm \alpha \vee$	uc vicc	

a plurality of address wiring formed on an insulating
substrate;

a gate insulating film formed on said address wiring;

a plurality of data wiring formed in a manner that said data wiring and said address wiring cross each other;

an upper layer insulating film grown on said data wiring;

a transparent electrode, composed of a transparent conductive film, formed on said upper layer insulating film and placed in each of picture element areas surrounded by said address wiring and said data wiring;

a thin-film transistor section, disposed in each of picture element areas, used to selectively connect said data wiring with said transparent electrode by a gate connected to said address wiring; and

a capacitor section, disposed in each of picture element areas, composed of a first electrode formed on said gate insulating film using the same conductive film as used for said data wiring, a second electrode formed on said upper layer insulating film using the same transparent conductive film as used for said transparent electrode and said upper layer insulating film.

1 2. The liquid-crystal display device according to 2 claim 1, wherein said second electrode is formed with an 3 extended part of said transparent electrode.

1

2

3

4

5

- 3. The liquid-crystal display device according to claim 1, wherein said first electrode is connected to said address wiring using the same transparent conductive film as used for said transparent electrode.
- 4. The liquid-crystal display device according to claim 1, wherein said first electrode is connected to said address wiring using the same conductive film as used for said data wiring.
  - 5. The liquid-crystal display device according to claim 1, wherein a part of said capacitor section is formed in a manner that it is superimposed through said gate insulating film on said address wiring.
  - 6. The liquid-crystal display device according to claim 1, wherein a width of said address wiring is constant in said picture element area and wherein said capacitor section is formed in a manner that the whole of it is superimposed through said gate insulating film on said address wiring.
- 7. The liquid-crystal display device according to claim 1, wherein the whole of said thin-film transistor section and of data wiring is covered with said upper layer insulating film or said transparent conductive film.
- 1 8. The liquid-crystal display device according to claim 1, wherein said upper layer insulating film is thinner than that of said gate insulating film or a dielectric constant

1

2

5

6

- of said upper layer insulating film is larger than that of said gate insulating film.
- 9. The liquid-crystal display device according to claim 1, wherein said upper layer insulating film is a complex film composed of a plurality of insulating films.
  - 10. The liquid-crystal display device according to claim 1, wherein said upper layer insulating film is composed of, at least, one kind of a silicon nitride film, silicon oxide film and metal oxide film.
  - 11. The liquid-crystal display device according to claim 1, wherein said auxiliary capacitive common wiring is formed in parallel to said address wiring and wherein said capacitor section is formed in a manner that it is partially or totally superimposed on said auxiliary capacitive common wiring.
- 1 12. The liquid-crystal display device according to claim 11, wherein connections are made at, at least, two points between said first electrode and said address wiring or between said first electrode and said auxiliary capacitive common wiring.
- 1 13. The liquid-crystal display device according to claim 1, wherein said capacitor section is formed by connecting, in parallel, a first capacitive component composed of a part of said address wiring, said first electrode and said gate

- 5 insulating film put between said address wiring and said first
- 6 electrode with a second capacitive component composed of said
- 7 first electrode, said second electrode and said upper layer
- 8 insulating film put between said first electrode and said second
- 9 electrode.

6

8

9

10

11

12

13

16

17

18

19

14. A method for producing the liquid-crystal display device of claim 1, comprising the steps of:

forming a plural ty of address wiring on an insulating substrate;

forming a gate insulating film on said address wiring;
forming a plurality of data wiring on said gate insulating
film in a manner that said data wiring and address wiring cross
each other;

forming a thin-film transistor used to selectively connect said data wiring with said transparent electrode disposed in each of picture element areas by a gate connected to said address wiring, in each of picture element areas surrounded by said address wiring and data wiring;

forming a first electrode using the same conductive film
as used for said data wiring;

forming an upper layer insulating film on said first electrode;

forming a second electrode using the same transparent conductive film as used for said transparent electrode; and

forming said capacitor section using said first electrode, 21 said second electrode and said upper layer insulating film.

1 15. The method for producing the liquid-crystal

- 2 display device according to claim 14, wherein said second
- 3 electrode is formed with an extended part of said transparent
- 4 electrode in aid capacitor section.
- 1 16. The method for producing the liquid-crystal 2 display device according to claim 14, wherein said first 3 electrode is connected to said address wiring using the same 4 transparent conductive film as used for said transparent 5 electrode.
  - 17. The method for producing the liquid-crystal display device according to claim 14, wherein said first electrode is connected to said address wiring using the same conductive film used for said data wiring.
- 1 18. A method for producing the liquid-crystal display 2 device of claim 11, comprising the steps of:
- forming a plurality of address wiring on an insulating substrate;
- forming a plurality of auxiliary capacitive common wiring
  in a manner that it is disposed in parallel to said address
- 7 wiring;
- forming a gate insulating film on said auxiliary gate capacitive common wiring;
- forming a plurality of data wiring on said gate insulating
- 11 film in a manner that said address wiring and data wiring cross
- 12 each other;
- forming a thin-film transistor used to selectively
- 14 connect said data wiring with said \transparent electrode

19

21

22

23

24

25

26

27

3

4

5

6

1

2

8

disposed in each of picture element areas by a gate connected 15 to said address wiring, in each of picture element areas 16 surrounded by said address wiring and data wiring; 17

forming said first electrode using the same conductive film as used for said data wiring;

forming said upper insulating film on said first electrode;

forming said second electrode using the same transparent conductive film as used for said transparent electrode; and

forming said capaditor section using said first electrode, said second electrode and said upper layer insulating film in a manner that said capacitor is partially or totally superimposed on said auxiliary capacitive common wiring.

1/J The method for producing the liquid-crystal display device of claim 13 according to claim 14, wherein said first electrode is connected to said transparent electrode and said second electrode is connected to said address wiring and wherein said capacitor section is mounted in a manner that it is superimposed on a part of said address wiring.

A method for producing the liquid-crystal display 20. device of claim 4, comprising the steps of:

forming a plurality of address wiring on an insulating substrate;

forming a gate insulating film on said address wiring; forming, in said gate insulating film, a through hole which reaches said address wiring

forming a plurality of data wiring on said gate insulating

3 7 film in a manner that said address wiring and data wiring cross

each other;

forming a thin-film transistor used to selectively connect said data wiring with said transparent electrode

disposed in each of picture element areas by a gate connected to said address wiring, in each of picture element areas surrounded by said address wiring and data wiring;

forming said first electrode using the same conductive film used for said data wiring;

connecting said first electrode to said address wiring via said through hole formed in said gate insulating film;

forming said upper layer insulating film on said first electrode;

forming said second electrode using the same transparent conductive film as used for said transparent electrode; and

forming said capacitor section using said first electrode, said second electrode and said upper layer insulating film.

add A2

all DE>